

Discrete POWER & Signal **Technologies**

BCW65C



This device is designed for general purpose amplifier applications at collector currents to 500 mA. Sourced from Process 19.

Absolute Maximum Ratings*

TA = 25°C unless otherwise.

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	32	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	1.0	A
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units	
		*BCW65C		
P_{D}	Total Device Dissipation	350	mW	
	Derate above 25°C	2.8	mW/°C	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W	

^{*}Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

NPN General Purpose Amplifier

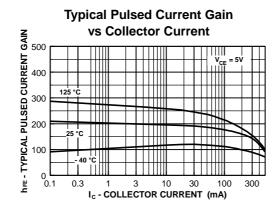
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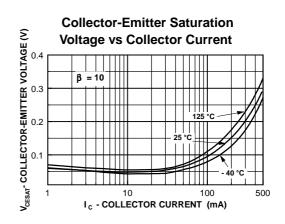
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TA = 25°C unless otherwise noted

$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Symbol	Parameter	Test Conditions	Min	Max	Units
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$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	OFF CHA	RACTERISTICS				
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	32		V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	60		V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{CES}	Collector-Cutoff Current				nA
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		F '' 0 . " 0				μA
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{EBO}	Emitter-Cutoff Current	$V_{EB} = 4.0 \text{ V}, I_{C} = 0$		20	nA
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	''FE	DC Current Gain	$I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$	180	630	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			I 400 A V 40 V	00		I
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$, 52	and the second	630	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$				The second secon	000	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	-		V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		D 5 % 0 4 % 1/4 %		11 11		.,
	V _{BE(sat)}	Base-Emitter Saturation Voltage			2.0	V
	SMALL SI	IGNAL CHARACTERISTICS	COM			
C_{ibo} Input Capacitance $V_{EB} = 0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$ 80 NF Noise Figure $I_C = 0.2 \text{ mA}, V_{CE} = 5.0,$ 10	f _T	Current Gain - Bandwidth Product	, 02	100		MHz
NF Noise Figure $I_C = 0.2 \text{ mA}, V_{CE} = 5.0,$ 10	C _{obo}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1.0 \text{ MHz}$		12	pF
, OL,	C _{ibo}	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz}$		80	pF
$R_{\rm S} = 1.0 \rm k\Omega$, f = 1.0 kHz,	NF	Noise Figure			10	dB
BW = 200 Hz			, ,			

Typical Characteristics

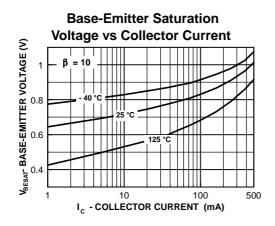


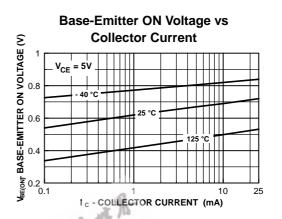


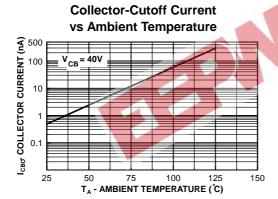
NPN General Purpose Amplifier

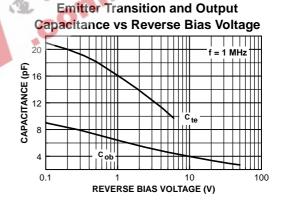
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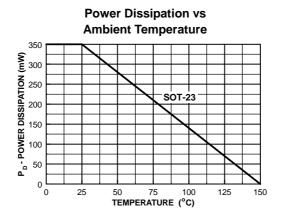
Typical Characteristics











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